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(57) **ABSTRACT**

A display device includes silver-molybdenum alloy electrodes having high reflectivity despite annealing temperatures. The display may have a first display substrate, a second display substrate and a liquid crystal layer. The first display substrate includes signal-applying modules (e.g., TFTs) disposed on a first substrate each including an output terminal configured to output a data signal, a patterned insulation layer having contact holes that expose the output terminals, and silver-molybdenum alloy electrodes (made of silver and molybdenum) electrically connected to the output terminals. The silver-molybdenum alloy electrode is employed in the display device, thereby increasing reflectivity of the display device and improving display quality of an image displayed by the display device.

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Jun. 23, 2005 (KR) 2005-54302

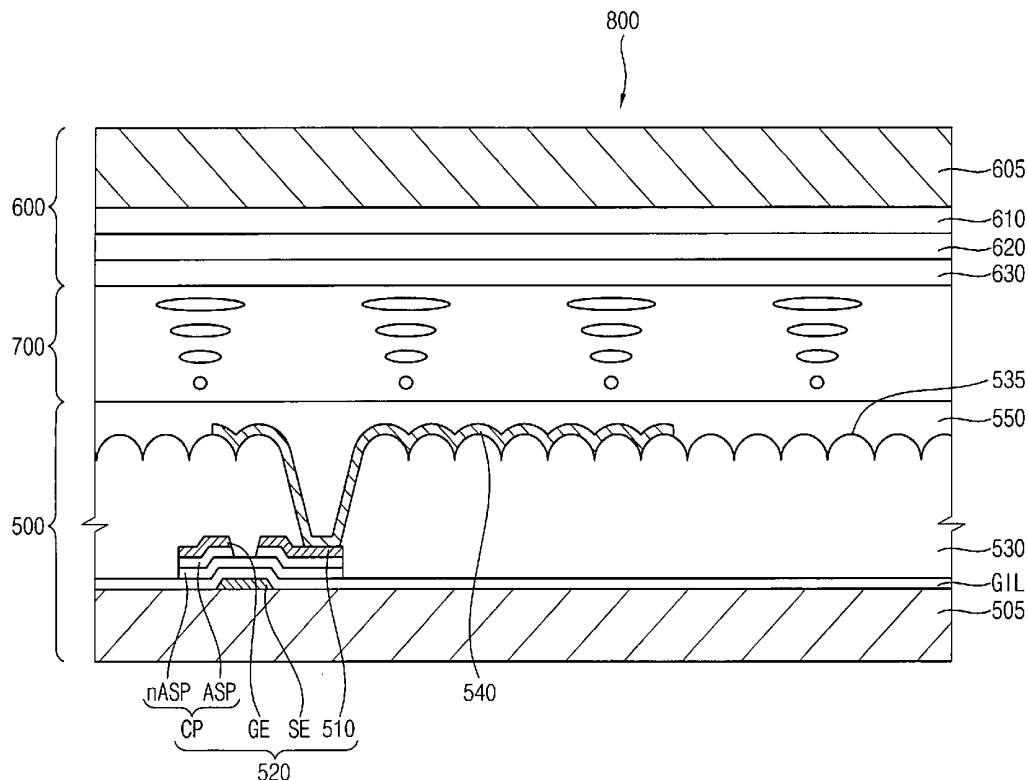


FIG. 1

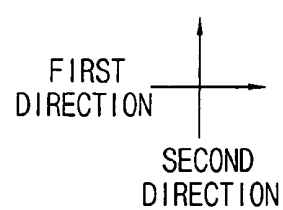
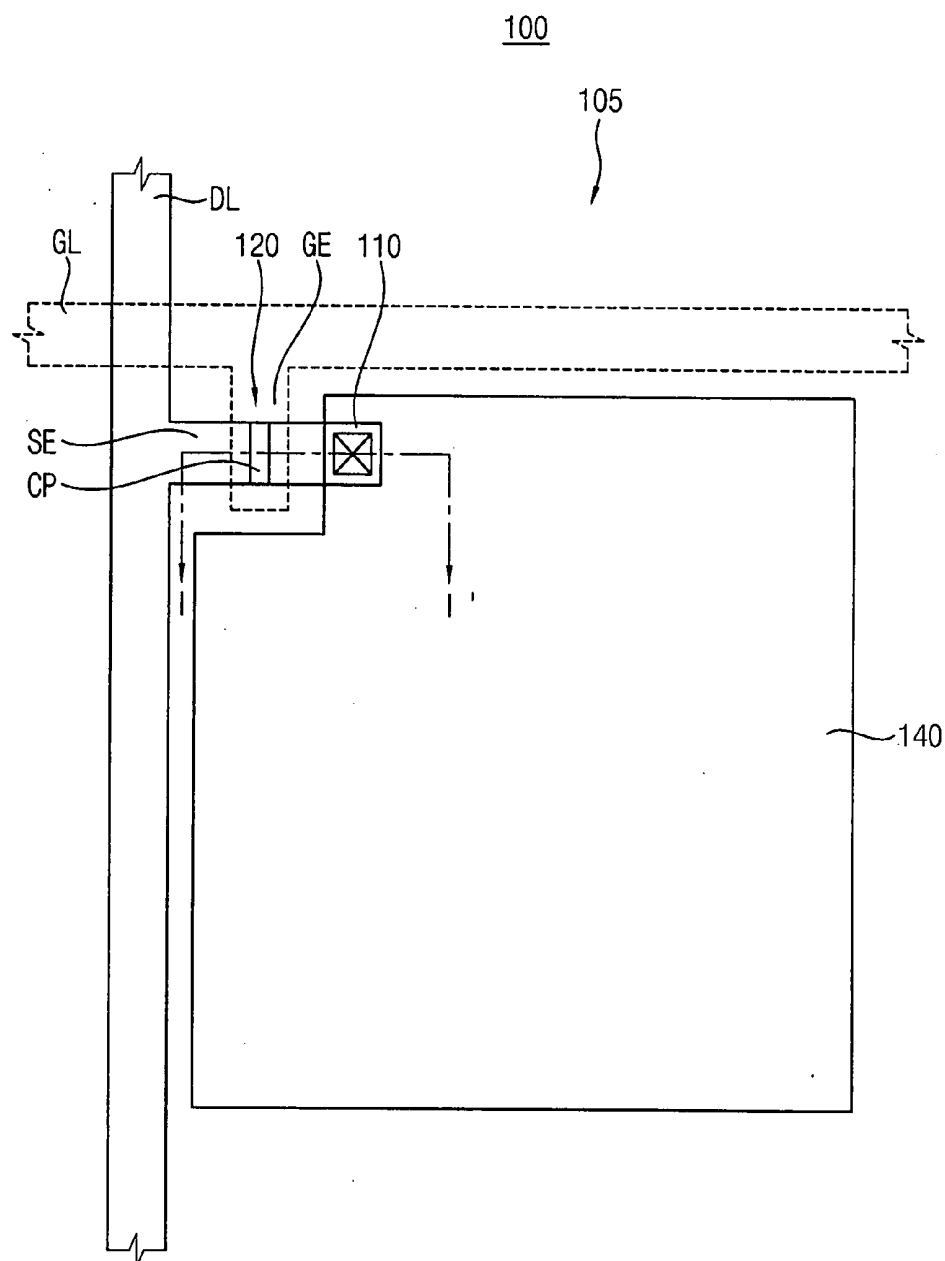


FIG. 4

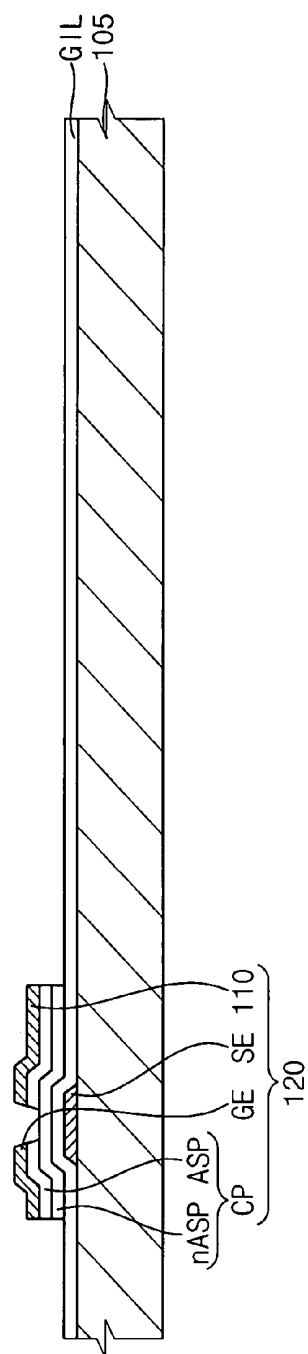


FIG. 5

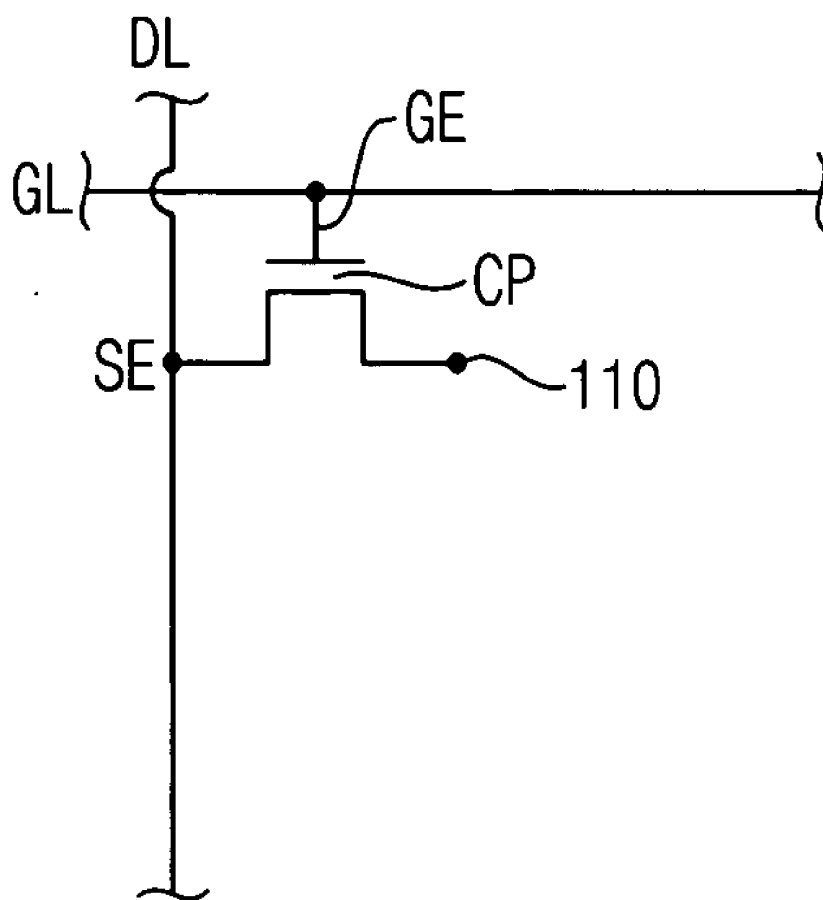


FIG. 6

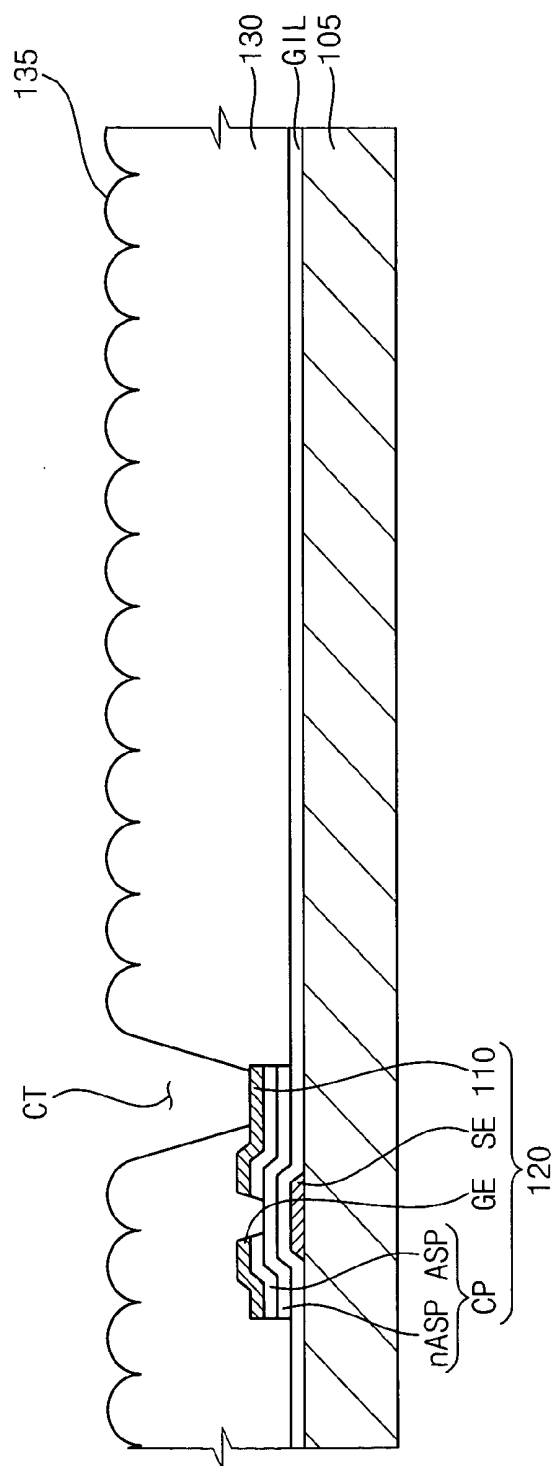


FIG. 7

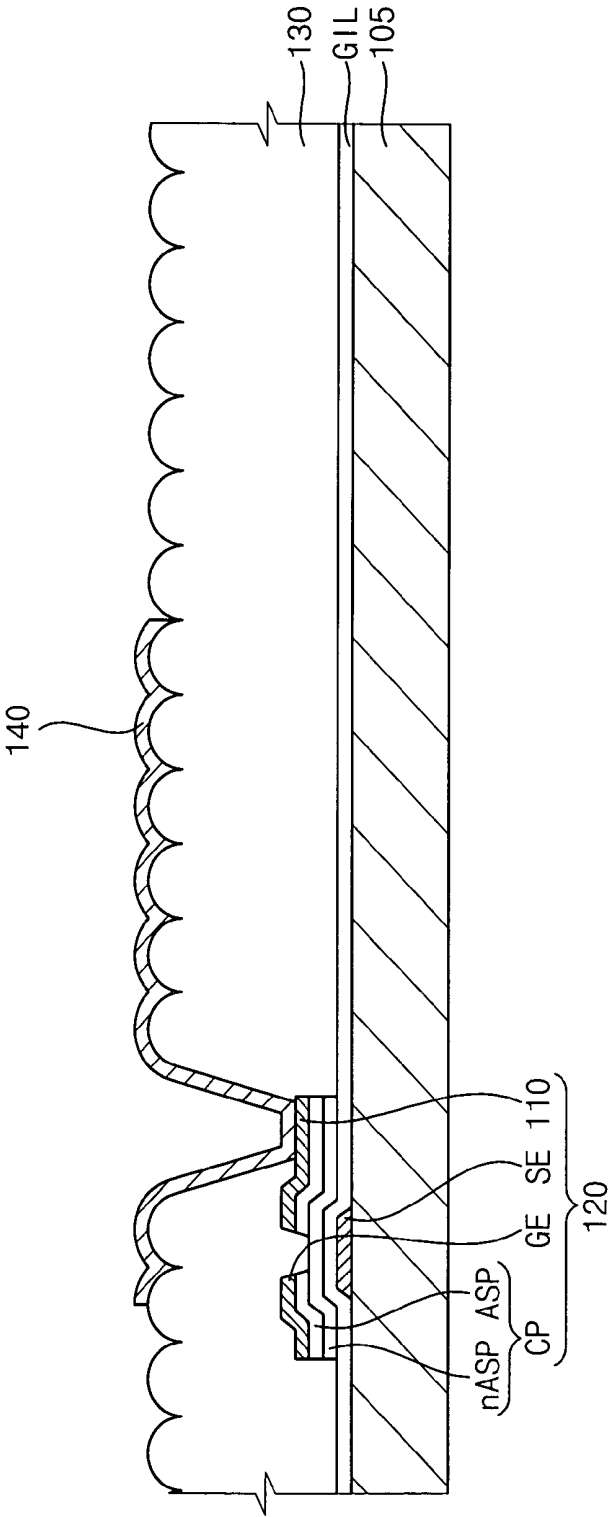


FIG. 8

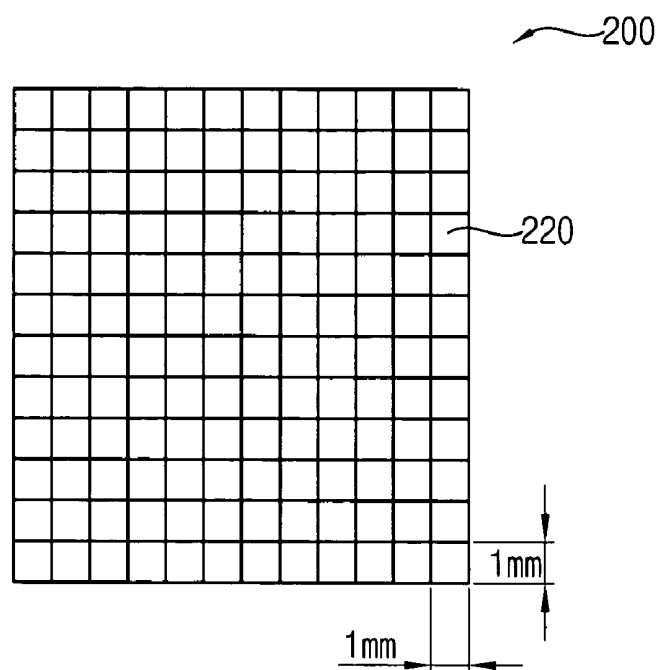


FIG. 9

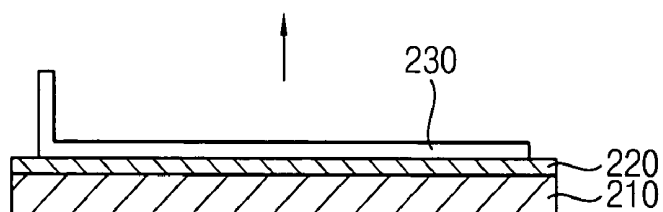


FIG. 10

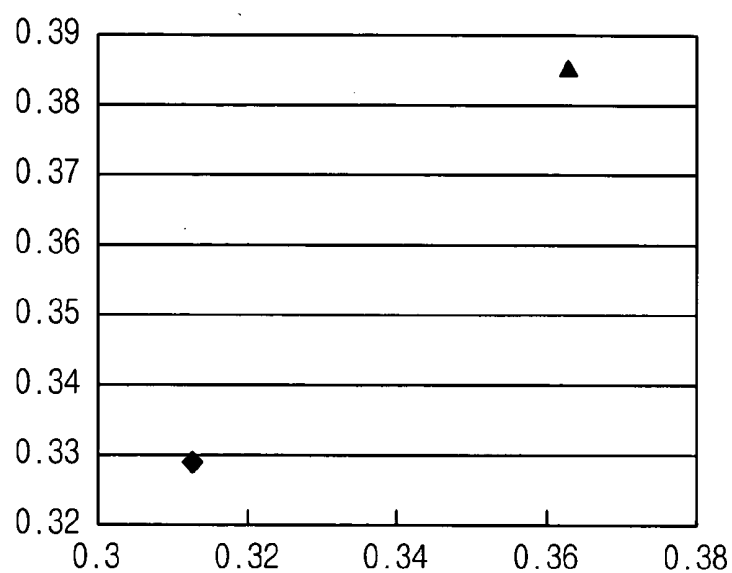


FIG. 11

	BEFORE ANNEALING	AFTER ANNEALING
PURE SILVER LAYER		
SILVER- MOLYBDENUM ALLOY LAYER		

FIG. 12A

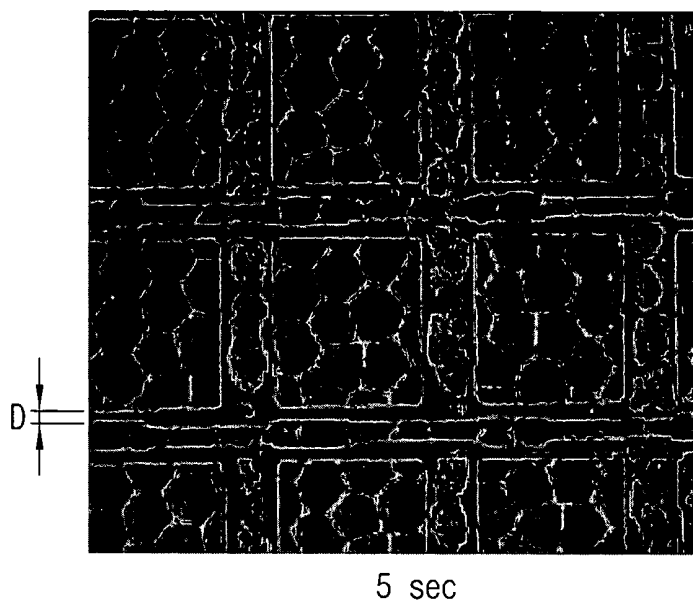


FIG. 12B

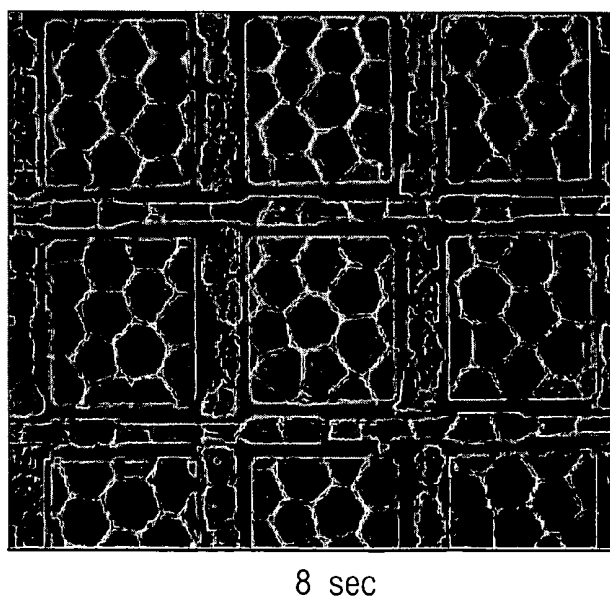
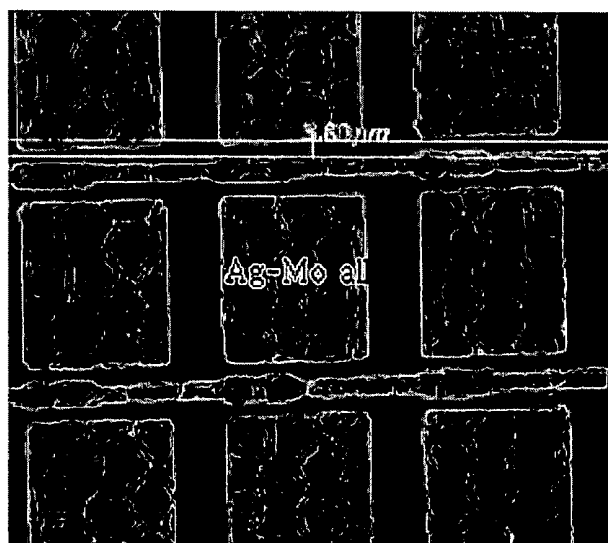


FIG. 12C



11 sec

FIG. 12D



17 sec

FIG. 13

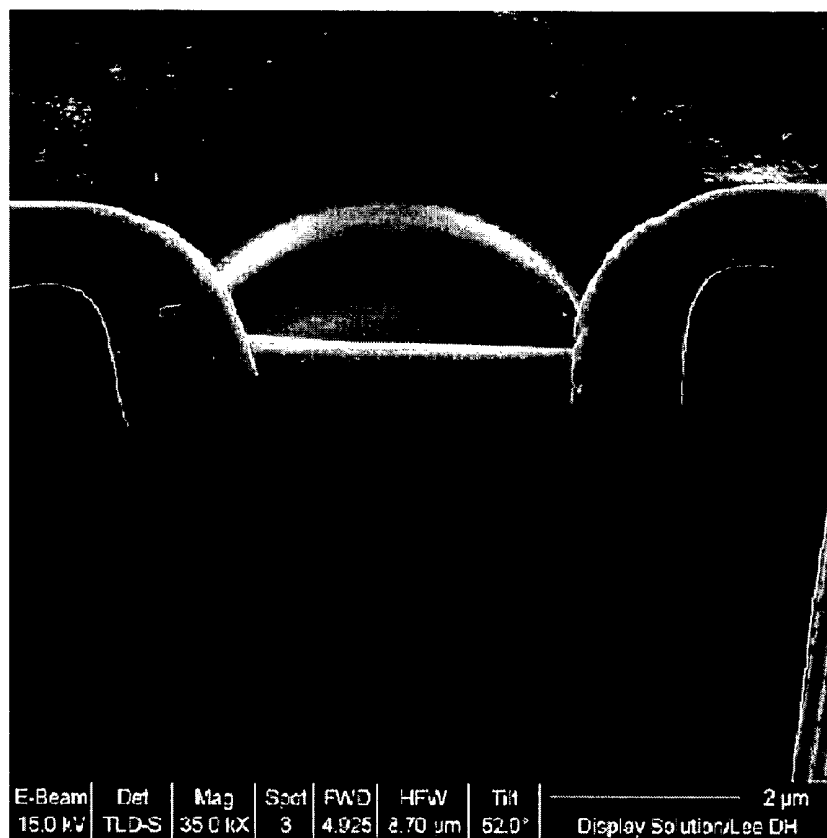


FIG. 14

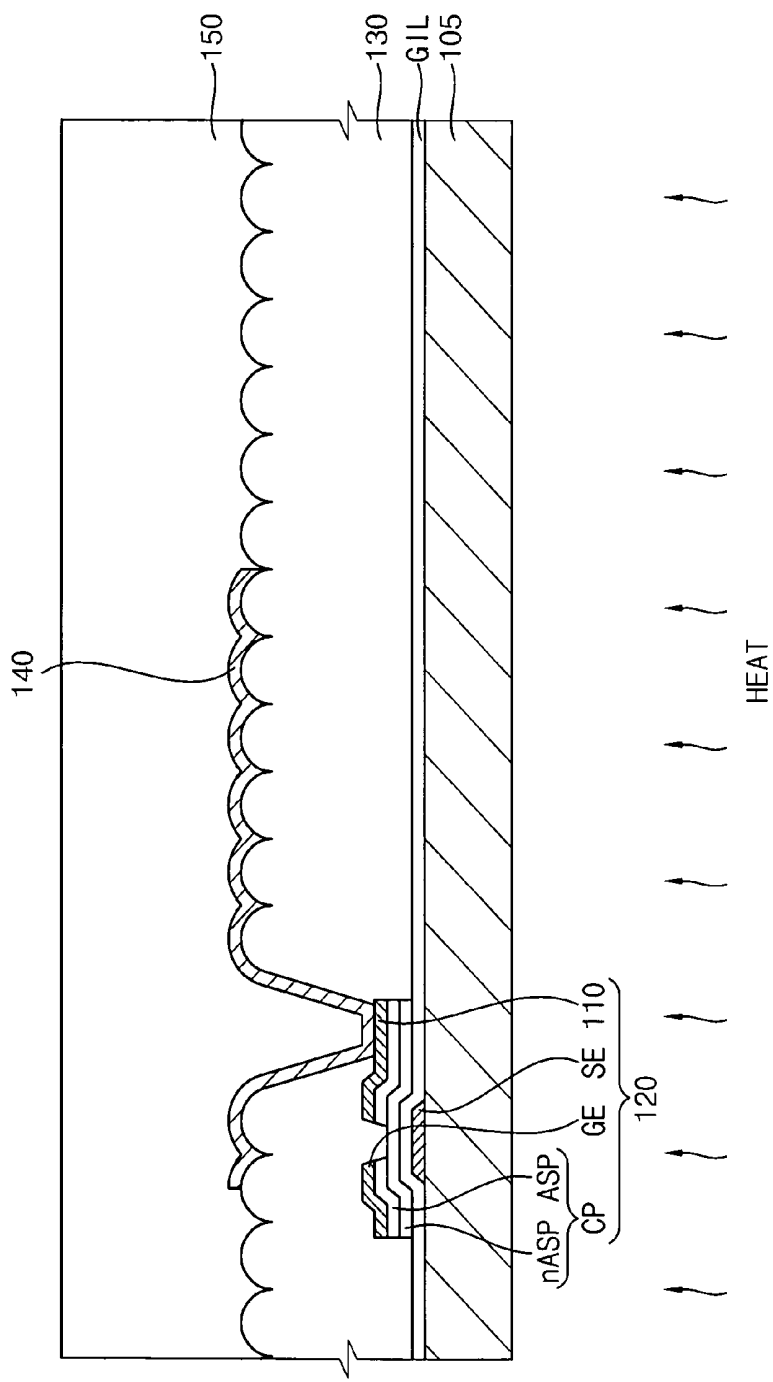


FIG. 15

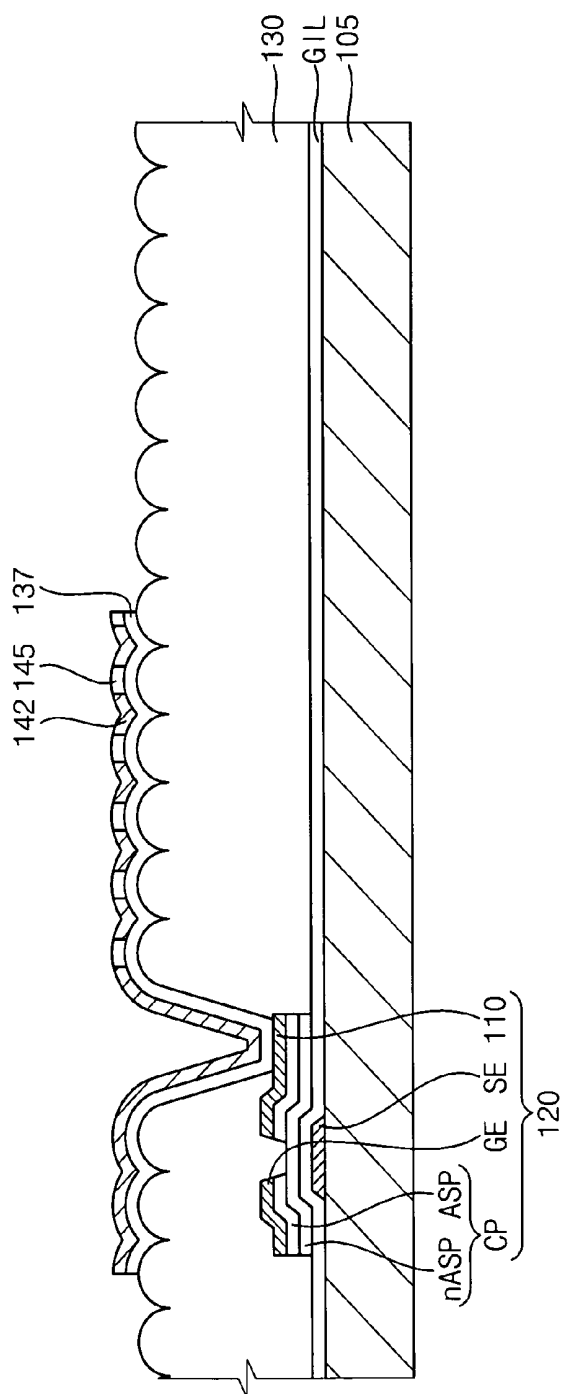
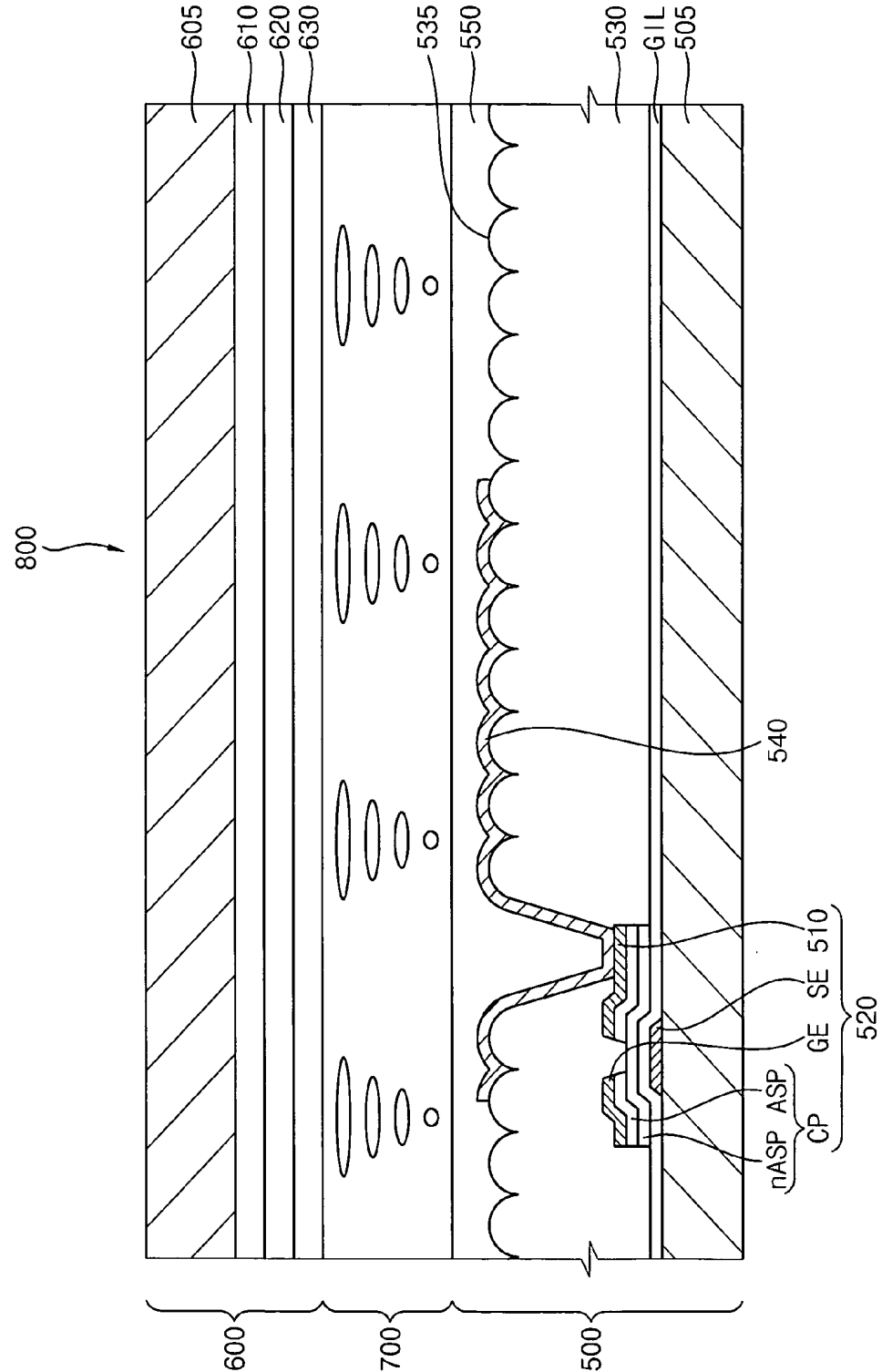


FIG. 16



**DISPLAY SUBSTRATE, METHOD OF
MANUFACTURING THE SAME AND DISPLAY
DEVICE HAVING THE SAME**

CROSS-REFERENCE TO RELATED
APPLICATIONS

[0001] This application relies for priority under 35 U.S.C. § 119 of Korean Patent Application No. 2005-54302 filed on Jun. 23, 2005, the entire contents of which are herein incorporated by reference.

BACKGROUND OF THE INVENTION

[0002] 1. Field of the Invention

[0003] The present invention relates to a display substrate, a method of manufacturing the display substrate and a display device having the display substrate. More particularly, the present invention relates to a display substrate capable of improving display quality of an image, a method of manufacturing the display substrate and a display device having the display substrate.

[0004] 2. Description of the Related Art

[0005] Generally, a display device converts information processed from an information processing device to an image.

[0006] Examples of the display devices include a cathode ray tube (CRT) type display device, a liquid crystal display (LCD) device, an organic light emitting display (OLED) device, etc.

[0007] Liquid crystal display (LCD) devices are classified into three types, a transmissive type LCD device, a reflective type LCD device, and a reflective-transmissive type LCD device, depending upon the method of using light.

[0008] The transmissive type LCD device displays an image using light provided from an internal lamp installed within the LCD device. The reflective type LCD device displays an image using light externally provided (e.g., from the sun, a lamp, or other illuminating device). The reflective-transmissive type LCD device displays an image using light internally provided from a lamp installed in the LCD device and/or externally provided.

[0009] The transmissive type LCD device includes a transparent electrode that is transparent and conductive, while the reflective type LCD device includes a reflective electrode that has a greater reflectivity than a transparent electrode. The reflective-transmissive type LCD device includes both a transparent electrode and a reflective electrode.

[0010] When the reflective electrode of the reflective type LCD device or the reflective-transmissive type LCD device includes aluminum or aluminum alloy having a high reflectivity (e.g., reflective electrodes made of aluminum or of aluminum alloy), hillocks may be formed on the surface of the reflective electrode (e.g., during a curing process for an alignment layer formed on the reflective electrode), and galvanic corrosion may occur between the reflective electrode and the transparent electrode.

[0011] Aluminum films are remarkably good for fabricating electrodes and lines because of their low resistivity, low cost, high adhesion, and superior patternability. However, the thermal expansion mismatch between Al films and a

substrate or layer of display panels produces a large compressive stress in the Al films upon heating, and results in the formation of hillocks (or whiskers) in order to relieve the stress.

[0012] In order to prevent the galvanic corrosion problem, a corrosion-proof layer may be formed between the reflective electrode and the transparent electrode. However, formation of the corrosion-proof layer requires a great increase in the number of manufacturing steps in a manufacturing process, which increases manufacturing costs.

SUMMARY OF THE INVENTION

[0013] An aspect of present invention provides a display substrate having a silver-molybdenum alloy electrode and capable of improved image display quality.

[0014] An aspect of the present invention provides a method of manufacturing the display substrate.

[0015] Another aspect of the present invention provides a display device having the display substrate.

[0016] In one aspect of the present invention, a display substrate includes a silver-molybdenum alloy electrode (e.g., per each pixel). The display substrate may include a signal-applying module (e.g., a thin-film transistor, TFT), a patterned insulation layer and a silver-molybdenum alloy electrode. The signal-applying module is disposed on a substrate and includes an output terminal (e.g., a TFT transistor-drain terminal) configured to output a data signal. The patterned insulation layer has a contact hole that exposes the output terminal. The silver-molybdenum alloy electrode is electrically connected to the output terminal and has silver and molybdenum.

[0017] In another aspect of the present invention, in order to manufacture a display substrate, a signal-applying module including an output terminal configured to output a data signal is formed on a substrate (e.g., for each pixel); a contact hole that exposes a portion of the output terminal is formed through an insulation layer covering the signal-applying module to form a patterned insulation layer; and a silver-molybdenum alloy layer electrically connected to the output terminal is formed on the patterned insulation layer. The silver-molybdenum alloy layer is patterned to form a silver-molybdenum alloy electrode (e.g., at each pixel of the display).

[0018] In still another aspect of the present invention, a display device includes a first display substrate (including a silver-molybdenum alloy electrode), and may further include a second display substrate and a liquid crystal layer. The first display substrate includes a signal-applying module (e.g., a TFT transistor) for each pixel on the first substrate (the signal-applying module including an output terminal configured to output a data signal), a patterned insulation layer having a contact hole that exposes the output terminal, and a silver-molybdenum alloy electrode (made of silver and molybdenum) electrically connected to the output terminal. The second display substrate includes a common electrode that is disposed on a second substrate facing the first substrate. The common electrode faces the silver-molybdenum alloy electrode. The liquid crystal layer is disposed between the first and second display substrates.

[0019] The present invention will be described more fully hereinafter with reference to the accompanying drawings, in

which embodiments of the invention are shown. This invention may, however, be embodied in many different forms and should not be construed as limited to the embodiments set forth herein; rather, these embodiments are provided so that this disclosure will be thorough and complete, and will fully convey the scope of the invention to those skilled in the art. In the drawings, the thickness of layers and regions are exaggerated for clarity. Like reference numerals refer to similar or identical elements throughout. It will be understood that when an element such as a layer, region or substrate is referred to as being "on", "upon" or "onto" another element, it may be directly on the other element or intervening elements may also be present.

BRIEF DESCRIPTION OF THE DRAWINGS

[0020] The above and other features and advantages of the present invention will become more apparent by describing in detailed exemplary embodiments thereof with reference to the accompanying drawings, in which:

[0021] FIG. 1 is a plan view of one pixel region of a display substrate according to an exemplary embodiment of the present invention;

[0022] FIG. 2 is a cross-sectional view taken along section line I-I' in FIG. 1;

[0023] FIG. 3 is a cross-sectional view of a pixel region of a display substrate according to another exemplary embodiment of the present invention;

[0024] FIG. 4 is a cross-sectional view of a display substrate for illustrating a method of manufacturing according to an exemplary embodiment of the present invention;

[0025] FIG. 5 is an equivalent circuit diagram illustrating the transistor (TFT) formed in the exemplary signal-applying module 120 illustrated in FIGS. 1, 2, 3 and 4;

[0026] FIG. 6 is a cross-sectional view illustrating a patterned insulation layer formed on the substrate 105 in FIG. 4;

[0027] FIG. 7 is a cross-sectional view illustrating a silver-molybdenum alloy electrode formed on the patterned insulation layer illustrated in FIG. 6;

[0028] FIG. 8 is a plan view of a test plate for adhesion testing a silver-molybdenum alloy layer according to an exemplary embodiment of the present invention;

[0029] FIG. 9 is a cross-sectional view of a portion of the test plate of FIG. 8 under test, for illustrating a method of performing the adhesion test in FIG. 8;

[0030] FIG. 10 is a graph showing color coordinates of a silver-molybdenum alloy layer before (diamond) annealing and after (triangle) annealing according to an exemplary embodiment of the present invention;

[0031] FIG. 11 shows four scanning electron microscope (SEM) pictures showing a pure silver layer and a silver-molybdenum alloy layer before and after annealing, according to an exemplary embodiment of the present invention;

[0032] FIGS. 12A, 12B, 12C and 12D are SEM pictures showing etching characteristics of a silver-molybdenum alloy layer;

[0033] FIG. 13 is an SEM picture illustrating a step coverage of the silver-molybdenum alloy layer;

[0034] FIG. 14 is a cross-sectional view of a first substrate illustrating an alignment layer formed on a patterned insulation layer according to an exemplary embodiment of the present invention;

[0035] FIG. 15 is a cross-sectional view of a first substrate illustrating a method of manufacturing a display substrate according to another exemplary embodiment of the present invention; and

[0036] FIG. 16 is a cross-sectional view of an assembled display device (comprising first display substrate, second display substrate, and a liquid crystal layer) according to an exemplary embodiment of the present invention.

DETAILED DESCRIPTION OF EXEMPLARY EMBODIMENTS OF THE INVENTION

[0037] Display Substrate

[0038] FIG. 1 is a plan view of a display substrate according to an exemplary embodiment of the present invention. FIG. 2 is a cross-sectional view taken along section line I-I' in FIG. 1.

[0039] Referring to FIGS. 1 and 2, a display substrate 100 includes a substrate 105, a signal-applying module 120 having an output terminal 110, a patterned insulation layer 130 and a silver-molybdenum alloy electrode 140.

[0040] The substrate 105 may be formed of a transparent substrate material such as a glass or other substrate material capable of passing light.

[0041] The signal-applying module 120 is disposed on the substrate 105. The signal-applying module 120 outputs image data that is externally provided.

[0042] As more particularly illustrated in FIG. 2, the signal-applying module 120 includes a gate line GL having a gate electrode GE, a gate insulation layer GIL, a channel pattern CP, a data line DL having a source electrode SE and the output terminal 110.

[0043] When the three-color display including display substrate 100 has a pixel resolution of 1024×768: a plurality (768) of gate lines GL extend substantially parallel to each other in a first (horizontal) direction that is substantially perpendicular to a second (vertical) direction; a plurality (1024×3) of data lines DL (each data line including 768 source electrodes SE) extend substantially parallel to each other in the second (vertical) direction; and, a plurality (1024×3) of gate electrodes GE protrudes from each of the (768) gate lines GL on the substrate 105, protruding in a direction that is substantially parallel with the second direction.

[0044] The gate insulation layer GIL covers the gate lines GL and the gate electrodes GE so as to insulate the gate lines GL from the data lines DL (including the source electrodes SE). The gate insulation layer GIL may include a transparent silicon nitride layer.

[0045] The channel pattern CP is formed as a semiconductor island upon the gate insulation layer GIL. The channel pattern CP, for example, is disposed on the gate insulation layer GIL in an area corresponding to the gate

electrode GE. The channel pattern (semiconductor island) CP includes an amorphous silicon pattern ASP and an n-amorphous silicon pattern nASP. A pair of n-amorphous silicon patterns nASP are disposed on the amorphous silicon pattern ASP, and spaced apart from each other. The channel pattern CP and the electrodes (gate electrode, source electrode, and output (drain) electrode) form a transistor (data switch), such as a thin-film-transistor (TFT).

[0046] The data lines DL are disposed on the gate insulation layer GIL. The data lines DL extend in the second (vertical) direction that is substantially perpendicular to the first (horizontal) direction. When the three-color including display substrate 100 has a resolution of 1024×768, a plurality of 1024×3 data lines DL having are substantially parallelly arranged in the first direction. A plurality of 768 source electrodes SE protrude from each data line DL in a direction that is substantially parallel with the first (horizontal) direction. Each source electrode SE is electrically connected to one of the n-amorphous silicon patterns nASP in the semiconductor island (channel pattern CP).

[0047] The output terminal 110 is electrically connected to the other of the n-amorphous silicon patterns nASP. The output terminal 110 is formed simultaneously with the data line DL.

[0048] The patterned insulation layer 130 is disposed on the substrate 105, so that the signal-applying module 120 is covered by the patterned insulation layer 130. The patterned insulation layer 130 includes, for example, a photosensitive material that is sensitized to light so as to form the contact hole. The patterned insulation layer 130 is patterned such that a contact hole exposing the output terminal 110 of the signal-applying module 120.

[0049] A plurality of textured patterns 135 is formed on the patterned insulation layer 130. The textured patterns 135 increase a reflective area of a silver-molybdenum alloy electrode 140 that will be described later, and diffuses light reflected from the silver-molybdenum alloy electrode 140. The textured patterns 135 may be formed by embossing (and thus be embossed patterns) or by other methods (e.g., scribing, or etching)

[0050] The silver-molybdenum alloy electrode 140 is formed (e.g., conformally) on the textured patterns 135 on the patterned insulation layer 130. A portion of the silver-molybdenum alloy electrode 140 is electrically connected (through the contact hole) to the output terminal 110 exposed by the contact hole.

[0051] The silver-molybdenum alloy electrode 140 may preferably be composed of about 99 percent by weight to about 95 percent by weight of silver (Ag) and about 1 percent by weight to about 5 percent by weight of molybdenum (Mo).

[0052] An alignment layer 150 is formed on the silver-molybdenum alloy electrode 140. The alignment layer 150 includes, for example, polyimide resin. Alignment grooves are formed on the alignment layer 150 to align liquid crystal molecules.

[0053] The alignment layer 150 including polyimide resin is cured at a temperature of about 150° C. to about 250° C.

[0054] Hillocks may not be formed on the surface of the silver-molybdenum alloy electrode 140 when the alignment

layer 150 is cured with a temperature of about 150° C. to about 250° C, thereby avoiding exfoliation of the silver-molybdenum alloy electrode 140 from the patterned insulation layer 130.

[0055] FIG. 3 is a cross-sectional view of a pixel region of a display substrate according to another exemplary embodiment of the present invention. The display substrate in FIG. 3 is substantially the same as the display substrate illustrated in FIGS. 1 and 2 except for a transparent electrode 137 and opening(s) 145 in the silver-molybdenum alloy electrode 142. Thus, any further descriptions for substantially the same elements will be omitted.

[0056] Referring to FIG. 3, a transparent electrode 137 that is transparent and conductive is formed on the patterned insulation layer 130. The transparent electrode 137 includes, for example, indium tin oxide (ITO), indium zinc oxide (IZO), amorphous indium tin oxide (a-ITO), etc. A portion of the transparent electrode 137 is electrically connected to the output terminal 110 that is exposed by a contact hole formed through the patterned insulation layer 130.

[0057] A silver-molybdenum alloy electrode 142 is disposed on the transparent electrode 137. The silver-molybdenum alloy electrode 142 may preferably have about 99 percent by weight to about 95 percent by weight of silver (Ag) and about 1 percent by weight to about 5 percent of by weight of molybdenum (Mo).

[0058] A plurality of openings 145 may be formed through the silver-molybdenum alloy electrode 142 down to the transparent electrode 137. Light may effectively pass through the openings 145, and through the transparent electrode 137. The openings 145, for example, may have a polygon perimeter shape when viewed from a plan view.

[0059] Method of Manufacturing a Display Substrate

[0060] FIG. 4 is a cross-sectional view of an (incomplete) display substrate, including a signal-applying module 120, for illustrating a method of manufacturing a display substrate (e.g., of FIGS. 1 & 2 or of 1 & 3) according to an exemplary embodiment of the present invention. FIG. 5 is an equivalent circuit diagram illustrating the transistor (TFT) formed in the signal-applying module 120 shown in FIGS. 1, 2, 3 and 4.

[0061] Referring to FIGS. 4 and 5, in order to manufacture a display substrate, firstly, a signal-applying module 120 is formed on a substrate 105.

[0062] In order to form the signal-applying module 120, a gate metal (not shown) is formed on the substrate 105 (e.g., through a chemical vapor deposition (CVD) process or a sputtering process). The gate metal is patterned (e.g., by a photolithography process) to form a gate line GL (and a gate electrode GE protruding from the gate line GL) on the substrate 105.

[0063] Then, a gate insulation layer GIL is formed on the substrate 105 (e.g., through a CVD process). The gate insulation layer GIL may include a transparent silicon nitride layer.

[0064] An n-amorphous silicon layer (not shown), an amorphous silicon layer (not shown) and a source/drain layer (not shown) are successively formed on the gate insulation layer GIL.

[0065] The source/drain layer is patterned (e.g., through a photolithography process) to form a data line DL having a source electrode SE and an output terminal 110 spaced apart from the source electrode SE on the n+amorphous silicon layer.

[0066] The n+amorphous silicon layer and the amorphous silicon layer are patterned using a mask of the data line DL and the output terminal 110 to form an n+amorphous silicon pattern nASP and an amorphous silicon pattern ASP on the gate insulation layer GIL.

[0067] FIG. 6 is a cross-sectional view illustrating a patterned insulation layer 135 formed on the substrate 105 in FIG. 4.

[0068] Referring to FIG. 6, a thick insulation layer (not shown) is formed on the substrate 105. The insulation layer includes, for example, an organic layer having photosensitive material. The insulation layer formed on the substrate 105 is patterned (e.g., by light passing through a predetermined mask) to form a patterned insulation layer 130. Textured patterns 135 are formed on (in) the patterned insulation layer 130, and a contact hole CT exposing a portion of the output terminal 110 of the signal-applying module 120 is formed through the patterned insulation layer 130.

[0069] FIG. 7 is a cross-sectional view illustrating a silver-molybdenum alloy electrode formed on the patterned insulation layer 130 patterned insulation layer shown in FIG. 6.

[0070] Referring to FIG. 7, a silver-molybdenum alloy layer (not shown) is formed on substantially the entire surface of the patterned insulation layer 130, including in the contact holes CT. Thus, a portion of the silver-molybdenum alloy layer is electrically connected to the output terminal 110 that is exposed by the contact hole CT formed through the patterned insulation layer 130. The silver-molybdenum alloy is formed, for example, through a CVD process or a sputtering process. The silver-molybdenum alloy layer may preferably have about 99 percent by weight to about 95 percent by weight of silver (Ag) and about 1 percent by weight to about 5 percent by weight of molybdenum (Mo).

[0071] The silver-molybdenum alloy layer may be patterned by a photolithography process to form a silver-molybdenum alloy electrode 140 on the patterned insulation layer 130. A portion of the silver-molybdenum alloy electrode 140 formed by patterning the silver-molybdenum alloy layer is electrically connected to the output terminal 110.

[0072] Hereinafter, various characteristics of the silver-molybdenum alloy layer according to an exemplary embodiment of the present invention will be described in detail.

[0073] Optical reflectivities of the silver-molybdenum alloy electrode and a pure aluminum electrode were measured.

[0074] In order to measure optical reflectivities of the silver-molybdenum alloy electrode and the pure aluminum electrode, textured patterns were formed on an organic layer, and then the silver-molybdenum alloy electrode and the pure aluminum electrode were formed on the textured patterns.

[0075] Table 1 below shows measurements of optical reflectivities, color coordinates and adhesivities of the silver-molybdenum alloy electrode and the pure aluminum

electrode. Table 1 indicates optical reflectivity of light that was reflected from each of the silver-molybdenum alloy electrode and the pure aluminum electrode, formed on the textured patterns.

TABLE 1

	Optical Reflectivity	Color Coordinates	Adhesion
Silver-molybdenum Alloy Electrode	73.0%	X = 0.1364 Y = 0.3359	Excellent
Pure Aluminum Electrode	60.4%	X = 0.3129 Y = 0.3307	Excellent

[0076] Referring to Table 1, the silver-molybdenum alloy electrode had a reflectivity 20% greater than that of the pure aluminum electrode, while an adhesivity of the silver-molybdenum alloy electrode to the organic layer was substantially the same as an adhesivity of the pure aluminum electrode to the organic layer.

[0077] FIG. 8 is a plan view of a test plate for adhesion testing a silver-molybdenum alloy layer formed according to an exemplary embodiment of the present invention. FIG. 9 is a cross-sectional view of a portion of the test plate of FIG. 8 under test, for illustrating a method of performing the adhesion test in FIG. 8.

[0078] Referring to FIGS. 8 and 9, a test plate 200 includes a base film 210 (FIG. 9) and a test film 220 (FIG. 9) formed on the base film 210.

[0079] The base film 210 includes, for example, glass, silicon oxide, indium tin oxide, polycarbonate, polyethylene terephthalate, acryl resin, polyimide, etc.

[0080] The test film 220 may include the silver-molybdenum alloy layer or a pure silver layer.

[0081] The test film 220 for an adhesion test is cut into about 1 mm×1 mm pieces using a cutter. After the test film 220 is formed into a lattice shape, an adhesive tape 230 is adhered to the test film 220, and then is peeled off the test film 220.

[0082] Table 2 below shows results from an adhesion test. In Table 2, symbols "○", "Δ" and "X" respectively indicate "no exfoliation", "exfoliation less than about 50%" and "exfoliation more than about 50%" (of the test film off of the base film).

TABLE 2

	Pure Silver	Silver-molybdenum Alloy	
	Deposition	Deposition	After Annealing
Glass	X	○	○ 250° C.
Silicon Oxide	X	○	○ 250° C.
Indium Tin Oxide	Δ	○	○ 250° C.
Polycarbonate	X	○	Not tested
PET	Δ	○	Not tested
Acryl Resin	X	○	○ 150° C.
Polyimide	—	○	○ 150° C.

[0083] Referring to Table 2, although the pure silver layer that served as the test film caused exfoliation irrespective of the base film, the silver-molybdenum alloy layer that served

as the test film caused no exfoliation irrespective of the base film. Therefore, adhesion of the silver-molybdenum alloy layer to the base film was much greater than that of the pure silver layer to the base film.

[0084] FIG. 10 is a graph showing color coordinates of a silver-molybdenum alloy layer before and after annealing according to an exemplary embodiment of the present invention. In FIG. 10, symbols “◆” (diamond) and “▲” (triangle) indicate color coordinates before baking and after baking, respectively.

[0085] Referring to FIG. 10, after the pure silver was baked, color coordinates of the pure silver were greatly changed. The pure silver became yellowish through baking. In contrast, after the silver-molybdenum alloy was baked, color coordinates of the silver-molybdenum alloy were almost unchanged, and thus an image color of a display device employing the silver-molybdenum alloy was also almost unchanged.

[0086] FIG. 11 shows four scanning electron microscope (SEM) pictures of a pure silver layer and a silver-molybdenum alloy layer before and after annealing, according to an exemplary embodiment of the present invention.

[0087] Referring to FIG. 11, after annealing the pure silver layer, hillocks were formed on the pure silver layer, making it uneven. When the pure silver layer has hillocks, externally provided light is irregularly scattered by the uneven surface of the pure silver layer, thereby greatly reducing its optical reflectivity. In contrast, after annealing the silver-molybdenum layer, the silver-molybdenum layer was still relatively even (smooth).

[0088] FIGS. 12A, 12B, 12C and 12D are SEM pictures showing etching characteristics of a silver-molybdenum alloy layer.

[0089] Referring to FIGS. 12A to 12D, when the silver-molybdenum alloy layer is etched using a conventional etchant (used for etching pure silver), the silver-molybdenum alloy layer was patterned to have a substantially uniform interval D of about 4 μm , and the optimum etching time was found to be about seventeen seconds. Thus, the silver-molybdenum alloy layer according to the present invention has good etching characteristics with respect to the conventional etchant.

[0090] FIG. 13 is an SEM picture illustrating a step coverage of the silver-molybdenum alloy layer.

[0091] Referring to FIG. 13, in order to observe a profile of the silver-molybdenum alloy layer positioned within a via hole (contact hole), the via hole having a thickness of about 5 μm was formed through an insulation layer. Then, an indium tin oxide layer and a silver-molybdenum alloy layer were successively deposited on the insulation layer having the via hole at thicknesses of about 70 nm and about 240 nm, respectively. The silver-molybdenum alloy layer had a good step coverage as shown in FIG. 13.

[0092] FIG. 14 is a cross-sectional view of a first substrate illustrating an alignment layer 150 formed on a patterned insulation layer 130 according to an exemplary embodiment of the present invention.

[0093] Referring to FIG. 14, an alignment layer 150 is formed on the patterned insulation layer 130. For example,

the alignment layer 150 includes polyimide resin. The alignment layer 150 may be baked at a temperature of about 150° C. to about 250° C. to prevent yellowing of the silver-molybdenum alloy layer and prevent formation of hillocks on the silver-molybdenum alloy layer.

[0094] FIG. 15 is a cross-sectional view of a first substrate illustrating a method of manufacturing a display substrate according to another exemplary embodiment of the present invention. The method of manufacturing a display substrate in FIG. 15 is substantially the same as the method of manufacturing a display substrate illustrated in FIGS. 4 and 14, except for a transparent electrode and an opening of in the silver-molybdenum alloy electrode. Thus, substantially the same elements will be represented by the same reference numerals and the same names.

[0095] Referring to FIG. 15, a transparent conductive layer (e.g., 137) is formed on substantially the entire surface of the patterned insulation layer 130, and a silver-molybdenum alloy layer (e.g., 142) is formed on the transparent conductive layer. Although the silver-molybdenum alloy layer is formed on the transparent conductive layer in FIG. 15, alternatively, the transparent conductive layer may be formed on the silver-molybdenum alloy layer.

[0096] The transparent conductive layer and the silver-molybdenum alloy layer, which are formed on the patterned insulation layer 130, are patterned (e.g., through a photolithography process) to form a transparent electrode 137 and a silver-molybdenum alloy electrode 142 on the patterned insulation layer 130. The transparent electrode 137 and the silver-molybdenum alloy electrode 142 are electrically connected to the output terminal 110 (of the TFT). The silver-molybdenum alloy electrode 142 may have a plurality of openings 145. The openings 145, for example, have a polygon shape when viewed from a plan view.

[0097] Display Device

[0098] FIG. 16 is a cross-sectional view illustrating an assembled display device (comprising first display substrate, second display substrate, and a liquid crystal layer) according to an exemplary embodiment of the present invention.

[0099] Referring to FIG. 16, a display device 800 includes a first display substrate 500, a second display substrate 600 and a liquid crystal layer 700.

[0100] The first display substrate 500 includes a first substrate 505, a signal-applying module 520 having an output terminal 510, a patterned insulation layer 530 and a silver-molybdenum alloy electrode 540.

[0101] The first substrate 505 includes a transparent substrate such as a glass substrate capable of passing light.

[0102] The signal-applying module 520 (of each pixel) is disposed on the first substrate 505. The signal-applying module 520 (of each pixel) outputs image data externally provided while the display is in use.

[0103] Particularly, the signal-applying module 520 includes a gate line (not shown) having a gate electrode GE, a gate insulation layer GIL, a channel pattern CP, a data line (not shown) having a source electrode SE and the output (drain) terminal 510.

[0104] The gate line extends, for example, in a first (e.g., horizontal) direction. When the first display substrate 500

has a resolution of 1024×768, a plurality of 768 gate lines are substantially parallelly distributed in a second direction that is substantially perpendicular to the first direction. A plurality of 1024×3 gate electrodes GE protrudes from each gate line on the first substrate **505**.

[0105] The gate insulation layer GIL covers the gate line having the gate electrode GE to insulate the gate line from the data lines having the source electrode SE. The gate insulation layer GIL may include a transparent silicon nitride layer.

[0106] The channel pattern CP (semiconductor island) is formed on the gate insulation layer GIL. The channel pattern CP, for example, is disposed on the gate insulation layer GIL corresponding to the gate electrode GE. The channel pattern CP includes an amorphous silicon pattern ASP and an n+amorphous silicon pattern nASP. A pair of n+amorphous silicon patterns nASP are disposed on the amorphous silicon pattern ASP, and spaced apart from each other.

[0107] The data lines are disposed on the gate insulation layer GIL. Each of the data lines extends in the second (vertical) direction that is substantially perpendicular to the first direction. When the first display substrate **500** has a resolution of 1024×768: there a plurality of 1024×3 data lines distributed in the first direction; a plurality of 768 source electrodes SE h protrudes from each data line on the first substrate **505**.

[0108] Each source electrode SE is electrically connected to one of the n+amorphous silicon patterns nASP. The output terminal **510** is electrically connected to the other of the n+amorphous silicon patterns nASP. The output terminal **510** is formed simultaneously with the data line.

[0109] The patterned insulation layer **530** is disposed on the first substrate **505**, so that the signal-applying module **520** is covered with the patterned insulation layer **530**. The patterned insulation layer **530** includes a contact hole exposing the output terminal **510** of the signal-applying module **520**. The patterned insulation layer **530** includes, for example, a photosensitive material that is sensitized to light so as to facilitate formation of the contact hole.

[0110] A plurality of textured (e.g., embossed) patterns **535** is formed on the patterned insulation layer **530**. The textured patterns **535** increase a reflective area of a silver-molybdenum alloy electrode **540** that will be described later, and diffuses light reflected from the silver-molybdenum alloy electrode **540**.

[0111] The silver-molybdenum alloy electrode **540** is formed on the textured patterns **535** on the patterned insulation layer **530**. A portion of the silver-molybdenum alloy electrode **540** is electrically connected to the output terminal **510** exposed by the contact hole.

[0112] The silver-molybdenum alloy electrode **540** may preferably have about 99 percent by weight to about 95 percent by weight of silver (Ag) and about 1 percent by weight to about 5 percent by weight of molybdenum (Mo).

[0113] An alignment layer **550** is formed on the silver-molybdenum alloy electrode **540**. The alignment layer **550** includes, for example, polyimide resin. Alignment grooves are formed on the alignment layer **550** to align liquid crystal molecules of the liquid crystal layer **700**.

[0114] The alignment layer **550** including polyimide resin is cured at a temperature of about 150° C. to about 250° C.

[0115] Hillocks may not be formed on the silver-molybdenum alloy electrode **540** when the alignment layer **550** is cured at the above temperature of about 150° C. to about 250° C., thereby preventing exfoliation of the silver-molybdenum alloy electrode **540** from the patterned insulation layer **530**.

[0116] The second display substrate **600** includes a second substrate **605**, a color filter **610**, (for example, formed on the second substrate **605**), a common electrode **620** formed on the color filter **610** and a second alignment layer **630**.

[0117] In FIG. 16, the color filter **610** is positioned to correspond to the silver-molybdenum alloy electrode **540** of the first display substrate **500**. The color filter **610** includes, for example, a red color filter for passing red light of white light, a green color filter for passing green light of white light, and a blue color filter for passing blue light of white light.

[0118] The common electrode **620** is formed on the color filter **610**. The common electrode **620** may include a transparent conductive material such as indium tin oxide, indium zinc oxide, amorphous indium tin oxide, etc. The common electrode **620** faces the silver-molybdenum alloy electrode **540** of the first display substrate **500**.

[0119] The second alignment layer **630** is positioned to face the first alignment layer **550**. Alignment grooves are formed on the second alignment layer **630** to align liquid crystal molecules of the liquid crystal layer **700**.

[0120] The liquid crystal layer **700** is disposed between the first display substrate **500** and the second display substrate **600**.

[0121] According to embodiments of the present invention, an electrode of a display device includes silver-molybdenum alloy, thereby improving display quality of an image displayed by the display device.

[0122] Although exemplary embodiments of the present invention have been described, it is understood that the present invention should not be limited to these exemplary embodiments but various changes and modifications can be made by one ordinary skilled in the art within the spirit and scope of the present invention as hereinafter claimed.

What is claimed is:

1. A display substrate comprising:

a signal-applying module disposed on a substrate and having an output terminal configured to output a data signal;

a patterned insulation layer having a contact hole that exposes the output terminal; and

a silver-molybdenum alloy electrode, comprising silver and molybdenum, electrically connected to the output terminal.

2. The display substrate of claim 1, wherein the signal-applying module further comprises:

a transistor-gate electrode protruding from a gate line that receives a timing signal;

a gate insulation layer configured to insulate the transistor-gate electrode;

a transistor channel in a semiconductor layer disposed on the gate insulation layer over the gate electrode; and

a transistor-source electrode protruding from a data line to input the data signal to the transistor channel,

wherein the output terminal is a transistor-drain terminal.

3. The display substrate of claim 1, wherein a textured pattern is formed on the patterned insulation layer.

4. The display substrate of claim 3, wherein the textured pattern is an embossed pattern.

5. The display substrate of claim 1, wherein the silver-molybdenum alloy electrode has about 99 percent by weight to about 95 percent by weight of silver (Ag) and about 1 percent by weight to about 5 percent by weight of molybdenum (Mo).

6. The display substrate of claim 1, wherein the silver-molybdenum alloy electrode has a plurality of openings having a polygon shape.

7. The display substrate of claim 6, wherein a transparent and conductive electrode is formed between the patterned insulation layer and the silver-molybdenum alloy electrode.

8. The display substrate of claim 7, wherein the transparent and conductive electrode includes at least one of indium tin oxide and indium zinc oxide.

9. A method of manufacturing a display substrate, comprising:

forming a signal-applying module on a substrate, the signal-applying module comprising an output terminal configured to output a data signal;

forming a patterned insulation layer covering the signal-applying module except for a contact hole that exposes a portion of the output terminal;

forming a silver-molybdenum alloy layer on the patterned insulation layer to be electrically connected, through the contact hole, to the output terminal; and

patterning the silver-molybdenum alloy layer to form a silver-molybdenum alloy electrode.

10. The method of claim 9, wherein the silver-molybdenum alloy layer has about 99 percent by weight to about 95 percent by weight of silver (Ag) and about 1 percent by weight to about 5 percent by weight of molybdenum (Mo).

11. The method of claim 9, wherein forming the patterned insulation layer further comprises embossing a pattern on the insulation layer.

12. The method of claim 9, further comprising forming a transparent and conductive electrode layer on the patterned insulation layer, after forming the patterned insulation layer and before forming the silver-molybdenum alloy layer.

13. The method of claim 12, wherein the silver-molybdenum alloy electrode has a plurality of openings.

14. The method of claim 9, further comprising, after forming the silver-molybdenum alloy electrode:

forming an alignment layer on the patterned insulation layer so as to cover the silver-molybdenum alloy electrode; and

baking the alignment layer at a temperature of about 150° C. to about 250° C.

15. The method of claim 9, further comprising, after forming the silver-molybdenum alloy electrode:

forming an alignment layer on the patterned insulation layer so as to cover the silver-molybdenum alloy electrode; and

baking the alignment layer at a temperature selected so as to prevent the silver-molybdenum alloy electrode from yellowing.

16. A display device comprising:

a first display substrate comprising:

a signal-applying module disposed on a first substrate and having an output terminal configured to output a data signal;

a patterned insulation layer having a contact hole that exposes the output terminal; and

a silver-molybdenum alloy electrode electrically connected to the output terminal.

17. The display device of claim 16, further comprising:

a second display substrate comprising a common electrode that is disposed on a second substrate facing the first substrate, the common electrode facing the silver-molybdenum alloy electrode; and

a liquid crystal layer disposed between the first and second display substrates.

18. The display device of claim 17, wherein the silver-molybdenum alloy electrode has about 99 percent by weight to about 95 percent by weight of silver (Ag) and about 1 percent by weight to about 5 percent by weight of molybdenum (Mo).

19. The display device of claim 17, wherein a transparent electrode is disposed in contact with the silver-molybdenum alloy electrode and the patterned insulation layer.

20. The display device of claim 19, wherein the transparent electrode is disposed between the silver-molybdenum alloy electrode and the patterned insulation layer.

21. The display device of claim 19, wherein the transparent electrode includes at least one of indium tin oxide and indium zinc oxide.

* * * * *

专利名称(译)	显示基板，其制造方法以及具有该显示基板的显示装置		
公开(公告)号	US20070081106A1	公开(公告)日	2007-04-12
申请号	US11/474112	申请日	2006-06-23
[标]申请(专利权)人(译)	CHO成奂 YUM浩南 CHOO DAE HO		
申请(专利权)人(译)	CHO朴成煥 YUM HO-NAM 秋dae-ho		
当前申请(专利权)人(译)	三星DISPLAY CO. , LTD.		
[标]发明人	CHO SUNG HWAN YUM HO NAM CHOO DAE HO		
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摘要(译)

显示装置包括尽管退火温度仍具有高反射率的银 - 铝合金电极。显示器可以具有第一显示基板，第二显示基板和液晶层。第一显示基板包括设置在第一基板上的信号施加模块（例如，TFT），每个第一基板包括配置成输出数据信号的输出端子，具有暴露输出端子的接触孔的图案化绝缘层，以及银 - 铝合金电极（由银和铝制成）电连接到输出端子。在显示装置中采用银 - 铝合金电极，从而提高了显示装置的反射率并改善了显示装置显示的图像的显示质量。

